

# TRANSISTOR (NPN)

### **FEATURES**

Switching transistor

MARKING: MMBT4401=2X

## MAXIMUM RATINGS (T<sub>A</sub>=25℃ unless otherwise noted)

Symbol	Parameter	Value	Units	
V <sub>CBO</sub>	Collector-Base Voltage	40	V	
V <sub>CEO</sub>	Collector-Emitter Voltage	40	V	
V <sub>EBO</sub>	Emitter-Base Voltage	5	V	
Ic	Collector Current -Continuous	0.6	Α	
Pc	Collector Power Dissipation	0.3	W	
Tj	Junction Temperature	150	$^{\circ}$	
T <sub>stg</sub>	Storage Temperature	-55-150	$^{\circ}$	

# SOT-23 1. BASE 2. EMITTER 3. COLLECTOR

## **ELECTRICAL CHARACTERISTICS (Tamb=25°C unless otherwise specified)**

Parameter	Symbol	Test conditions	MIN	MAX	UNIT
Collector-base breakdown voltage	V <sub>(BR)CBO</sub>	I <sub>C</sub> =-100μA , I <sub>E</sub> =0	40		V
Collector-emitter breakdown voltage	V <sub>(BR)CEO</sub>	I <sub>C</sub> = -1mA , I <sub>B</sub> =0	40		V
Emitter-base breakdown voltage	V <sub>(BR)EBO</sub>	I <sub>E</sub> =-100μA, I <sub>C</sub> =0	5		V
Collector cut-off current	I <sub>CBO</sub>	V <sub>CB</sub> =-35V, I <sub>E</sub> =0		0.1	μA
Collector cut-off current	I <sub>CEO</sub>	V <sub>CE</sub> =-35 V, I <sub>B</sub> =0		0.1	μA
Emitter cut-off current	I <sub>EBO</sub>	V <sub>EB</sub> =-4V,I <sub>C</sub> =0		0.1	μA
DC current gain	h <sub>FE</sub>	V <sub>CE</sub> =-2V, I <sub>C</sub> = -150mA	100	300	
Collector-emitter saturation voltage	V <sub>CE(sat)</sub>	I <sub>C</sub> =-150mA, I <sub>B</sub> =-15mA		0.4	V
Base-emitter saturation voltage	V <sub>BE(sat)</sub>	I <sub>C</sub> =- 150mA, I <sub>B</sub> =-15mA		0.95	V
Transition frequency	f <sub>T</sub>	$V_{CE}$ = -10V, $I_{C}$ = -20mA $f$ = 100MHz	250		MHz





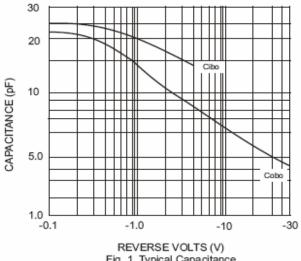
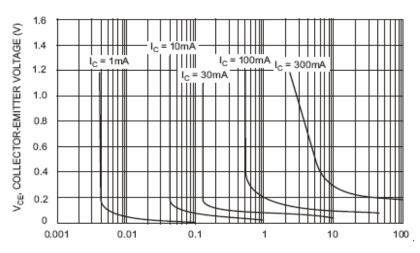
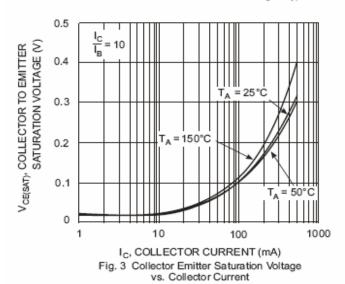
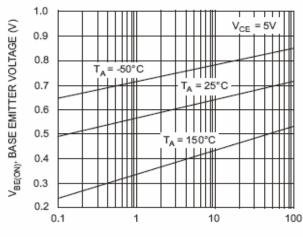


Fig. 1 Typical Capacitance



I<sub>B</sub>,BASE CURRENT (mA) Fig. 2 Typical Collector Saturation Region

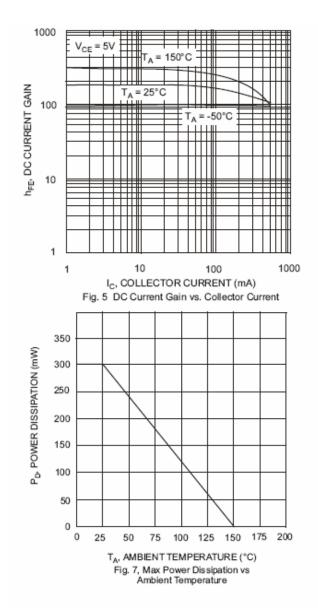


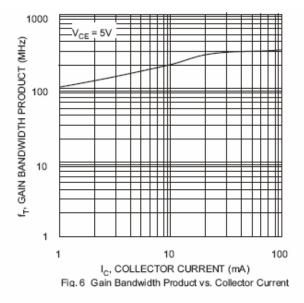


I<sub>C</sub>, COLLECTOR CURRENT (mA) Fig. 4 Base-Emitter Voltage vs. Collector Current









3



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